2

N/a

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No

Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material: Metal **Overall Length:** Between 0.250 inches and 0.450 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 3.5 gate trigger voltage, dc and 0.7 on-state voltage, dc **Current Rating Per Characteristic:** 16.00 amperes forward current, total rms nanoamperes and 40.00 milliamperes forward current, total rms preset Maximum Operating Tempurature Per Measurement Point: 85.0 degrees celsius case **Terminal Type And Quantity:** 1 case and 2 uninsulated wire lead w/terminal lug **Specification Data:** 80131-release3983 professional/industrial association specification Shelf Life: Unit Of Measure: **Demilitarization:** Fiig: A110a0